

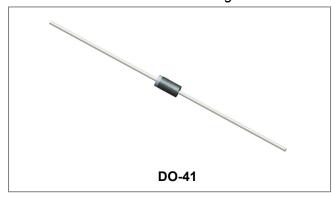




FR101G THRU FR107G

FAST RECOVERY GLASS PASSIVATED RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Amperes



Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- · Fast switching for high efficiency
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 260 C/10 seconds,0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension
- Glass passivated chip junction
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: JEDEC DO-41 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-202, Method 208
- Polarity: Color band denotes cathode end
- Mounting Position: AnyWeight: 0.34 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	FR 101G	FR 102G	FR 103G	FR 104G	FR 105G	FR 106G	FR 107G	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	$V_{RRM} \ V_{DC}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at @T _A =55°C	I _(AV)	1.0			Α				
Peak forward surge current 8.3ms single half sinewave superimposed on rated load (JEDEC Method)	I _{FSM}	30				А			
Maximum instantaneous forward voltage at 1.0A	V _F	1.3			V				
Maximum DC reverse current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	5.0 100			μA				
Maximum reverse recovery time (Note 1)	trr	150		250	5	00	ns		
Typical Junction Capacitance (Note 2)	CJ	15			pF				
Typical Thermal Resistance Junction to Ambient (Note 3)	R _{θJA}	40			°C/W				
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150			°C				

- Note: 1. Reverse recovery condition IF=0.5A, IR=1.0A, Irr=0.25A
 - 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 - 3. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted
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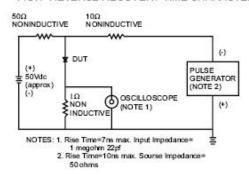


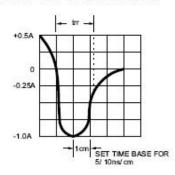


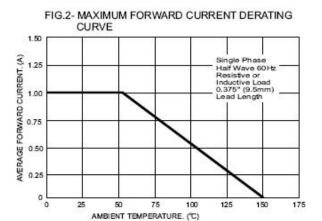


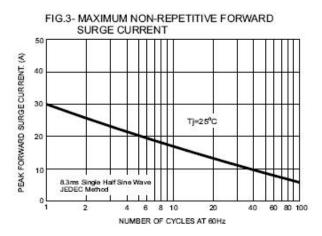
Ratings and Characteristics Curves

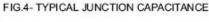
FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

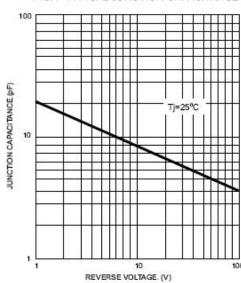




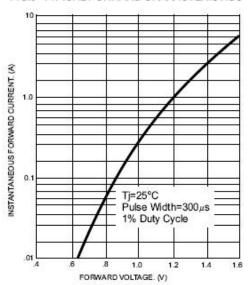












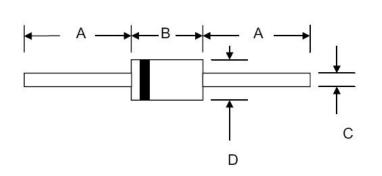
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Mechanical Dimensions DO-41



SYMBOL	Millim	neters	Inches			
OTMBOL	Min.	Max.	Min.	Max.		
А	25.4	-	1.000	-		
В	4.06	5.21	0.160	0.205		
С	0.71	0.864	0.028	0.034		
D	2.00	2.72	0.079	0.107		

Ordering Information

Device	Package	Shipping		
FR101G-FR107G	DO-41 (Pb-Free)	5000pcs / tape		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 FR101G
 = Part Name

 SSG
 = SSG

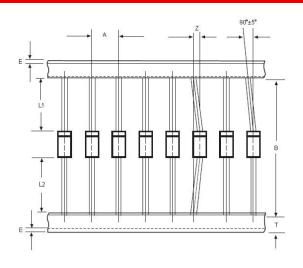
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-41



SYMBOL	Millimeters			
	Min.	Max.		
А	4.50	5.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

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